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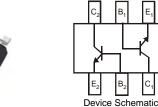
DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- **Epitaxial Planar Die Construction**
- Complementary PNP Type Available (MMDT4126)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device (Notes 5 and 6)

Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic, "Green" Molding Compound, Note 6. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating) Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)



Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	V_{CEO}	25	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Collector Current – Continuous (Note 1)	lc	200	mA

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Power Dissipation	(Notes 1 & 2)	P_{D}	200	mW
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{ hetaJA}$	625	°C/W
Operating and Storage and Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

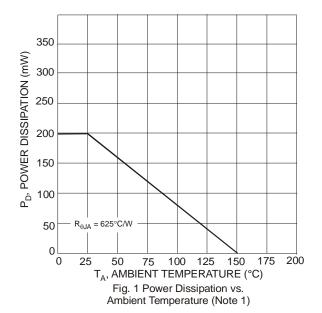
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	30		V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	25		V	$I_C = 1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	5.0		V	$I_E = 10 \mu A, I_C = 0$
Collector Cutoff Current	I _{CBO}		50	nA	$V_{CB} = 20V, I_{E} = 0V$
Emitter Cutoff Current	I _{EBO}		50	nA	$V_{EB} = 3.0V, I_C = 0V$
ON CHARACTERISTICS (Note 4)					
DC Current Gain	h	120	360		$I_C = 2.0 \text{mA}, V_{CE} = 1.0 \text{V}$
DC Current Gain	h _{FE}	60	_		$I_C = 50 \text{mA}, V_{CE} = 1.0 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.30	V	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}		0.95	V	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C_{obo}	_	4.0	pF	$V_{CB} = 5.0V$, $f = 1.0MHz$, $I_E = 0$
Input Capacitance	C_{ibo}	_	8.0	pF	$V_{EB} = 0.5V$, $f = 1.0MHz$, $I_{C} = 0$
Small Signal Current Gain	h _{fe}	120	480	_	$V_{CE} = 1.0V$, $I_{C} = 2.0mA$, $f = 1.0kHz$
Current Gain-Bandwidth Product	f _T	300		MHz	V _{CE} = 20V, I _C = 10mA, f = 100MHz
Noise Figure	NF	_	5.0	dB	$V_{CE} = 5.0V$, $I_{C} = 100\mu A$,
Noise Figure	INF				$R_S = 1.0k\Omega$, $f = 1.0kHz$

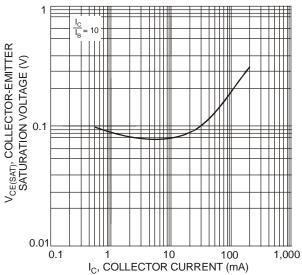
Notes:

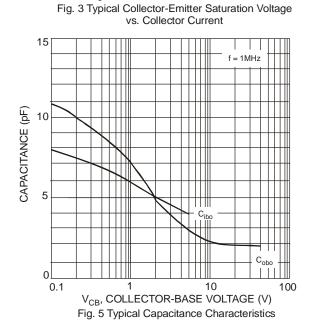
- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- Maximum combined dissipation.
- No purposefully added lead.
- Short duration pulse test used to minimize self-heating effect.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

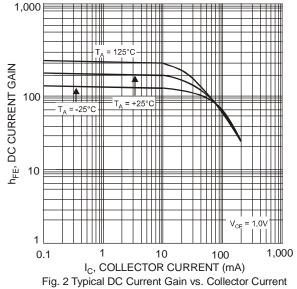
Document number: DS30164 Rev. 10 - 2











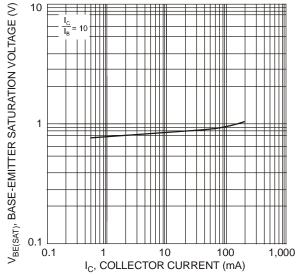


Fig. 4 Typical Base-Emitter Saturation Voltage vs. Collector Current

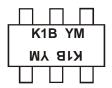


Ordering Information (Note 5)

Part Number	Case	Packaging
MMDT4124-7-F	SOT-363	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



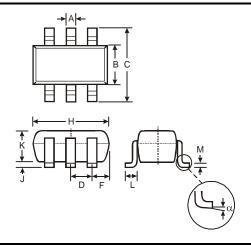
K1B = Product Type Marking Code YM = Date Code Marking Y = Year (ex: N = 2002)

M = Month (ex: 9 = September)

Date Code Kev

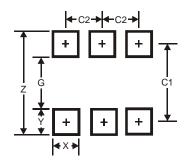
_	Date Code No	y																	
	Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015
	Code	J	K	L	M	Ν	Р	R	S	Т	J	>	W	Χ	Υ	Z	Α	В	С
_																			
	Month	Jan		Feb	Maı	r	Apr	May	/	Jun	Jul	l .	Aug	Sep		Oct	Nov	,	Dec
Γ	Code	1		2	3		4	5		6	7		8	9		0	N		D

Package Outline Dimensions



SOT-363					
Dim	Min	Max			
Α	0.10	0.30			
В	1.15	1.35			
C	2.00	2.20			
D	0.65	Тур			
F	0.40	0.45			
Н	1.80	2.20			
7	0	0.10			
K	0.90	1.00			
L	0.25	0.40			
М	0.10	0.22			
α	0°	8°			
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Υ	0.6
C1	1.9
C2	0.65

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